

Operation and Service Manual

350 MHz Preamplifier

SIM914



Stanford Research Systems

Revision 1.4 • May 23, 2003

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Printed in U.S.A.



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1 Operation

The SIM914 is a two-channel, 350 MHz, DC-coupled amplifier. This chapter provides general instructions on its use.

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1.1 Description

The SIM914 is a two-channel, 350 MHz bandwidth, DC-coupled, 50 Ω amplifier with a gain of 5 \times (+14 dB). The two channels may be cascaded for a gain of 25 \times (+28dB). The unit uses BNC connectors for inputs and outputs (see Figure 1.1). A rear panel DB-15 connector provides power to the unit.



Figure 1.1: The SIM914 front and rear panels.

The full scale input is ± 200 mV. The input noise (above 1 kHz) is typically $5.2 \text{ nV}/\sqrt{\text{Hz}}$. The output is linear over ± 1 V and should be terminated into a 50 Ω load. Output rise and fall times are 1.3 ns. The output will recover from a 10 \times full-scale overload within 3 ns. The unit is protected from ± 50 V, 1 μs input overloads.

The SIM914 is powered by ± 5 VDC from the SIM900 Mainframe. There are three LEDs on the front panel. The green LED indicates that power is present. The red LEDs indicate that the output signal for the corresponding channel is outside its linear range, typically ± 1.3 VDC. Brief overloads (<5 ns) trigger a 10 ms flash and will set the overload status bit in the mainframe.

1.2 Operation

The SIM914 is typically installed in the SIM900 Mainframe, which can accommodate up to eight SIM914s (plus one remote unit.) The unit is on, as indicated by the front-panel Power LED, whenever the mainframe has line power and is turned on.

The input impedance for each channel is 50 Ω . The DC input voltage must be limited to ± 4 V to avoid damaging the amplifier front-end. The amplifier is internally protected from 50 V transients of 1 μ s duration. The 50 Ω input impedance is intended to terminate 50 Ω coaxial cable such as RG-58.

The amplifiers perform well when cascaded due to their high input return loss and flat frequency response characteristics. Referenced to the input, the broadband noise (1 Hz to 300 MHz) is 80 μ Vrms. Peak-to-peak noise is typically 5 times the rms value. This corresponds to about 10 mVpp at the output of two cascaded amplifiers, 50 mVpp at the output of three cascaded amplifiers, and 250 mVpp at the output of four cascaded amplifiers.

1.3 SIM Interface Connector

The DB-15 SIM Interface Connector provides power and overload monitoring to the instrument. The connector signals are specified in the table below.

Pin	Name	Description
1	SIGNAL_GND	Ground
2	-STATUS	Overload (TTL output, active low)
6	-5V	Power supply
8	PS_RTN	Ground
9	CHASSIS_GND	Chassis ground
13	+5V	Power supply

Table 1.1: SIM Interface Connector pin assignments, DB-15. All other pins are left unconnected on the SIM914.

1.3.1 Grounding

In the SIM914, all three ground lines (Pins 1, 8 & 9) are tied common to the chassis, and also form the signal ground.

1.3.2 Direct Interfacing

The SIM914 is intended for operation in the SIM900 Mainframe, but users may wish to directly interface the module to their own systems without the use of additional hardware.

The mating connector needed is a standard DB-15 receptacle, such as Amp part # 747909-2 (or equivalent). Clean, well-regulated supply voltages of ± 5 VDC must be provided, with +5 V supplied on Pin 13 and –5 V supplied on Pin 6 (see Table 1.1). Ground may be provided on any combination of Pins 1, 8 or 9. The –STATUS signal may be monitored on Pin 2 for a low-going TTL-compatible output indicating an amplifier overload condition.

The SIM914 has no internal protection against reverse polarity, missing supply, or overvoltage on the power supply pins.

1.4 Specifications

		Min	Typ	Max	Units
Inputs (50 Ω source)	Input signal level	-200		+200	mV
	Impedance	49.5	50	50.5	Ω
	Return loss		32		dB
	Offset	-500		+500	μ V
	Offset drift	-10		+10	μ V/ $^{\circ}$ C
	Bias current (note 1)		3	10	μ A
	Protection (DC)	-4		+4	VDC
	Protection (1 μ s transient)	-50		+50	V
	Recovery time (10 \times FS overload)		3		ns
	Noise (10 Hz)		22		nV/ \sqrt Hz
	Noise (100 Hz)		8.6		nV/ \sqrt Hz
	Noise (>1 kHz)		5.2		nV/ \sqrt Hz
	Noise (1 Hz to 300 MHz BW)		80		μ Vrms
	Crosstalk (CH1 out to CH2 in)		-61		dB
	Crosstalk (CH2 out to CH1 in)		-82		dB
Amplifier	Gain (note 2)	4.95	5.00	5.05	V/V
	Bandwidth (-3 dB)		350		MHz
	Rise/fall time		1.3		ns
	Propagation delay		2.7		ns
Outputs (into 50 Ω)	Source impedance	49.5	50	50.5	Ω
	Linear operation	-1.0		+1.0	V
	Overload level	-1.3		+1.3	V
	Limit level	-1.6		+1.6	V
General	Number of Channels		2		
	Operating temperature	0		40	$^{\circ}$ C
	Weight		1.4		lbs
	Power		\pm 5		VDC
	Supply current		80		mA
	Dimensions	1.5" W \times 3.6" H \times 7.0" D			

Notes:

1. The input bias current flows out of the unit, creating a positive offset of about 150 μ V on the 50 Ω input termination. This offset will be affected by the DC impedance of the source that is connected to the input.
2. Amplifier gain is calibrated by applying a known current to the input and measuring the voltage into a high impedance load. The gain is adjusted so that a 1 mA source applied to the input produces a 500 mV voltage at the unloaded output.

2 Calibration

This chapter describes how to adjust the SIM914 for optimum performance. The module should be warmed up for at least 15 minutes before making any adjustments.

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2.1 General

The purpose of calibration is to verify operation of the unit and to:

- Adjust the high frequency compensation for best pulse response.
- Adjust the offset to null the DC voltage at the output with no input.
- Adjust the gain to $10\times$ for an unloaded output so that the nominal gain for an amplifier driving a $50\ \Omega$ load will be $5\times$ (+14dB).

Since the adjustments are interdependent, it is important that the adjustments be done in the prescribed order, and that all of the adjustments be done. For example, adjusting the high frequency compensation will affect the output offset.

2.2 Required Equipment

1. Pulse generator, splitter and attenuator to produce ± 100 mV square waves with a rise time of less than 1ns. (DG535 Digital Delay/Pulse Generator, AB output, into unmatched tee driving two $50\ \Omega$ cables with a 20 dB attenuator on the one that goes to the SIM914.)
2. Digital multimeter with 4-wire ohm measurement capability (Agilent 34401).
3. Oscilloscope with at least 300 MHz bandwidth.

2.3 High Frequency Compensation

The SIM914 uses an AD8009 current feedback amplifier in the output stage. The gain of the amplifier is controlled by the ratio of resistors in the feedback network and the bandwidth is controlled by the Thevenin equivalent source impedance of the feedback network. The ratio is fixed (by R115 & R116 or R215 & R216) to provide a gain of $5\times$ and the source impedance may be adjusted (by P102 and P202).

The bandwidth is set to optimize the pulse response of the amplifier. This is done by applying a fast pulse at the input and adjusting P102 (or P202 for Channel 2) so that the output rise time and overshoot most closely match the rise time and overshoot of the fast input pulse as observed on a 300 MHz oscilloscope with $50\ \Omega$ input impedance.

Note that adjusting P102 will affect the offset for Channel 1, as there is a large input bias current ($150\ \mu\text{A}$ max) to the inverting input of

the AD8009. The offset will need to be adjusted *after* the HF compensation is adjusted.

1. Split the pulse output from from the DG535 (set to 1 V amplitude) with a coax tee. Take one cable from the tee to channel 1 of the oscilloscope (set to 50 Ω input termination) and the other to the top channel of the SIM914 via a 20 dB coaxial attenuator.
2. Adjust P102 (Channel 1 “HF COMP” pot) to match the output rise time and overshoot to the input rise time and overshoot.
3. Repeat for Channel 2, adjusting the pulse response with P202.

2.4 Offset Calibration

The output offset is affected by the HF compensation and so the offset should be nulled after the HF compensation is adjusted. The offset may also be affected by the amplifier gain adjustment if there is a large input offset voltage.

1. Leave the inputs unconnected.
2. Connect the output (without a 50 Ω load) to the DMM on the millivolt DC range.
3. Adjust P101 (Channel 1 “OFFSET” pot) to null the output voltage.
4. Verify that the output voltage shifts down by less than 2.5 mV when a 50 Ω terminator is placed on the input. (The voltage shift $\Delta V_{\text{out}} = 10 \times i_b \times \Delta R_s$, where i_b is the input bias current, and ΔR_s is the change in input source impedance, here 25 Ω . This confirms that the input bias current $i_b < 10 \mu\text{A}$.)
5. Repeat the procedure to null the output of Channel 2 by adjusting P201.

2.5 Gain Calibration

The overall gain of the amplifier is 5 \times when driving a 50 Ω load and 10 \times when driving a high impedance load. The input source to the amplifier is typically a current source (such as the output from a photomultiplier tube) and so the magnitude of the input resistance is included in the gain calibration by measuring the transimpedance. (Calibration is done with a current source as an input while measuring the voltage at the output.)

A DMM used in the 4-wire resistance mode is convenient for performing the calibration. Typically a DMM will measure small resistances by measuring the voltage across the resistor while passing a

1 mA DC current through the resistor. We measure the gain of the amplifier by measuring the voltage at the output while applying test current to input. When the gain is properly adjusted, 1 mA applied to the $50\ \Omega$ input generates 50 mV at the input and 500 mV at the (unterminated) output causing the DMM to indicate a “resistance” of $500\ \Omega$. (To avoid auto ranging confusion by the DMM, a $453\ \Omega$ resistor is placed in series with the current source.)

Since the DMM uses a DC current as the test source, it is important that the amplifier offset be nulled prior to performing the DC gain adjustment.

1. Setup the DMM in the 4-wire resistance measurement mode.
2. Apply the current output to the Channel 1 input via a $453\ \Omega$ in-line resistor.
3. Apply the unterminated Channel 1 output to the DMMs 4-wire sense input.
4. Adjust P100 (Channel 1 “GAIN” pot) so that the DMM indicates a “resistance” of $500\ \Omega$.
5. Verify that the offset was nulled by connecting the current source from the DMM to the input of the other channel and measuring a resistance of less than $1\ \Omega$.
6. Repeat the gain adjustment for Channel 2 by adjusting P200.

3 Circuit Description

This chapter gives a general discussion of the circuitry in the SIM914.

The two amplifier channels are identical. This description uses reference designators in the top channel, Channel 1.

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3.1 Input Stage

The input is terminated into $50\ \Omega$ by the parallel combination of R100 & R101. The input signal is coupled via a $47\ \Omega$ resistor to the high speed “clamp-amp,” U100. U100 is configured as a non-inverting gain $2\times$ amplifier. Pins 8 & 5 on U100 define input clamping thresholds of $\pm 0.31\ \text{V}$. If the input signal exceeds these thresholds then U100 will use the clamping thresholds as inputs, thereby limiting the output to $\pm 0.62\ \text{V}$. This prevents the output of U100 from overdriving the next gain stage.

Input signals in excess of $\pm 1.4\ \text{V}$ are shunted to ground via the input protection diodes D100 & D101. Normally both the diodes in D100 are reversed biased and so they do not interfere with the signal. The diodes in D101 are forward biased by R103 & R104. When the input signal exceeds $\pm 1.4\ \text{V}$ ($7\times$ the full scale input), one of the diodes in D100 will begin to conduct, thereby limiting the input to U100 to a safe level.

The gain of U100 can be adjusted by $\pm 10\ \%$ by P100, which is calibrated at the factory to set the overall gain of the channel to $5\times$ when terminated into a $50\ \Omega$ load. The output of U100 is passed to the next gain stage via R112, a $47\ \Omega$ resistor.

3.2 Output Stage

The next stage has a fixed gain of $5\times$ with an adjustable offset and adjustable high frequency response. The gain of U101 is set by R115 & R116. The offset, adjusted by P101 and injected by R117, is nulled at the factory. The high frequency response of U101 is affected by the source impedance of its input signal and its feedback network. Turning P102 clockwise decreases the source impedance of the feedback signal and increases the high frequency response of the gain stage. P102 is adjusted at the factory for an optimum pulse response providing a typical -3dB bandwidth of $350\ \text{MHz}$.

The output from U101 is passed to the front-panel output BNC via the parallel resistors R118 & R119, providing a $50\ \Omega$ output impedance. These resistors, in combination with the $50\ \Omega$ load resistor (provided by the user), attenuate the signal by $2\times$ so that the overall gain is $5\times$.

3.3 Overload Detection

Overloads are detected at the output of the second gain stage, U101. A positive overload is rectified by D102 and charges C107. A negative overload is rectified by D102 and discharges C106. One of the

comparators in U102 will be driven low when the voltage on C106 or C107 exceeds ± 1.7 V. The driven comparator discharges C108 from +5 V to -5 V. C108 will be slowly recharged to +5 V by R128, a 1 M Ω resistor, thereby stretching the overload signal to about 10 ms. One of the comparators in U300 drives the front-panel overload LED until the voltage on C108 recharges above ground. This overload detection will detect overloads as short as 3 ns.

The overload detectors are wire-ord by D303 which will pull the status pin (pin 2 on the rear-panel connector to the SIM mainframe) to 0 V via the 3.9 V Zener diode when an overload occurs. The status pin may be polled via the SIM900 Mainframe to detect overloads in the unit.

3.4 Power

The ± 5 VDC power supplies are filtered at the rear panel (by L1, L3, C1 & C2), again on the main PCB (by L2, L4, C300 & C301), and finally at each channel of the amplifier (L100, L101, C110 & C111 for the top channel and L200, L201, C210 & C211 for the bottom channel.) Careful power supply filtering is important to reduce channel crosstalk. The crosstalk from the output of Channel 1 to the input of Channel 2 is less than -60dB (1:1000 of the amplitude) and peaks around 300 MHz. The crosstalk from the output of Channel 2 to the input of Channel 1 is less than -80dB (1:10,000 of the amplitude) and occurs in a broad band between 180 MHz and 360 MHz.

3.5 Parts List

Qty	Reference	SRS P/N	Part	Qty	Reference	SRS P/N	Part
8	C1,C2,C110,C111,C210, C211,C300,C301	5-00472	4.7U-35T	2	J303,J304 mounting	0-00259	4-40X1/2PP
5	C3,C106,C107,C206,C207	5-00375	100P	3	J305,J306,J307 mounting	0-00241	4-40X3/16 PP
12	C100,C101,C102,C103,C104, C105,C200,C201,C202,C203, C204,C205	5-00299	.1U	2	J303,J304 mounting	0-00042	4-40 HEX
2	C108,C208	5-00298	.01U	2	J303,J304 mounting	0-00043	4-40 KEP
1	D1	3-01429	MMBZ5228B	2	DB-15 mounting	0-00835	4-40X3/8PF
6	D100,D101,D102,D200,D201, D202	3-00896	BAV99L	4	Front panel mounting	0-00148	4-40X1/8,PS
1	D300	3-00424	LED-G	4	Rear panel mounting	0-00515	4-40X1/8PP
2	D301,D302	3-00425	LED-R	8	Module Cover Mounting	0-00371	4-40X3/16P
1	D303	3-00649	MBAW56L	1	Front Panel, SIM914	7-00987	
1	J1	1-00367	DB15-GND	1	Lexan FP Overlay, SIM914	7-01353	
4	J100,J101,J200,J201	1-00003	BNC	1	Rear Panel, SIM914	7-01410	
1	J311 TO J312	1-00483	Jumper 4X1 (2")	2	SIM 1X BRACKET	7-00933	
1	J2-J5	1-01042	Jumper 4X1 (4")	2	SIM Module Cover	7-00932	
8	L1,L2,L3,L4,L100,L101, L200,L201	6-00236	BEAD	4	Foot	0-00188	SR550FOOT
2	P100,P200	4-00487	20				
2	P101,P201	4-00011	10K-10T				
4	R103,R104,R203,R204	4-01503	10K				
2	P102,P202	4-00353	100-10T				
9	R1,R105,R107,R121,R125 R205,R207,R221,R225	4-01455	100				
4	R2,R300,R307,R308	4-01479	1K				
12	R100,R101,R109,R110,R118, R119,R200,R201,R209,R210, R218,R219	4-01021	100/1%				
4	R102,R112,R202,R212	4-01447	47				
8	R106,R108,R122,R123,R206, R208,R222,R223	4-01134	1.50K				
2	R115,R215	4-01050	200/1%				
2	R116,R216	4-01280	49.9				
2	R117,R217	4-01213	10.0K				
4	R120,R124,R220,R224	4-01527	100K				
4	R126,R127,R226,R227	4-01163	3.01K				
2	R128,R228	4-01551	1M				
2	U100,U200	3-00897	AD8037				
2	U101,U201	3-00898	AD8009				
3	U102,U202,U300	3-00728	LM393				
1	PCB	7-00967	SIM914 Rev C				

3.6 Schematic Diagrams

Schematic diagrams follow this page.